NSN 5961-01-282-9859

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In	closure Material:
PI	astic
0	verall Length:
0.	620 inches
Τe	erminal Length:
0.	562 inches
0	verall Height:
0.	190 inches
0	verall Width:
0.4	405 inches
M	ounting Facility Quantity:
1	
In	ternal Configuration:
Fi	eld effect
Jo	pint Electronic Device Engineering Council/jedec/case Outline Designation:
Тс	p-220ab
M	ounting Method:
Τe	erminal and unthreaded hole
Se	emiconductor Material:
Si	licon
Vo	oltage Rating In Volts Per Characteristic:
60	0.0 drain to source voltage
С	urrent Rating Per Characteristic:
4.	00 amperes drain current
Po	ower Rating Per Characteristic:
20	0.0 watts total device dissipation
M	aximum Operating Tempurature Per Measurement Point:
15	50.0 degrees celsius junction
Τe	erminal Type And Quantity:
3	pin
Sł	helf Life:
N/	/a
Uı	nit Of Measure:
De	emilitarization:
No	0
Fi	ig:
A1	110a0